

## 1.2A, 1.4MHz, Dual Synchronous DC-DC Buck Converter AP3423

### General Description

The AP3423 is a dual high-efficiency, 1.4MHz fixed frequency, current mode, PWM synchronous buck (step-down) DC-DC converter, capable of driving a 1.2A load with high efficiency, excellent line and load regulation.

The AP3423 integrates synchronous P-channel and N-channel power MOSFET switches with low on-resistance. It is ideal for portable applications powered from a single Li-ion battery. 100% duty cycle and low on-resistance P-channel internal power MOSFET can maximize the battery life.

The switching frequency of AP3423 is 1.4MHz, which allows small-sized components, such as capacitors and inductors. A standard series of inductors from several different manufacturers are available. This feature greatly simplifies the design of switch-mode power supplies.

The AP3423 is available in DFN-3×3-12 package.

### Features

- Dual Channel DC-DC Converter
- Independent Enable Control
- Input Voltage Range: 2.5 to 5.5V
- Adjustable Output from 0.6 to  $V_{IN}$
- 0.6V Reference Voltage with  $\pm 2\%$  Precision
- Output Current: 1.2A
- High Efficiency: up to 95%
- Low  $R_{DS(ON)}$  Internal Switches
- Operation Frequency: 1.4MHz
- Current Mode Control
- 100% Duty Cycle
- Built-in Soft-start
- Built-in UVLO Function
- Built-in Short Circuit Protection
- Built-in Current Limit Function
- Built-in Thermal Shutdown Protection
- DFN-3×3-12 package

### Applications

- Portable Media Player
- Digital Still and Video Cameras
- Notebook

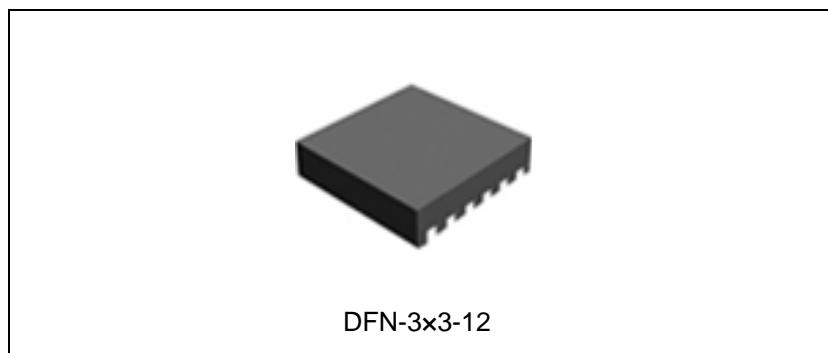


Figure 1. Package Type of AP3423

## 1.2A, 1.4MHz, Dual Synchronous DC-DC Buck Converter AP3423

### Pin Configuration

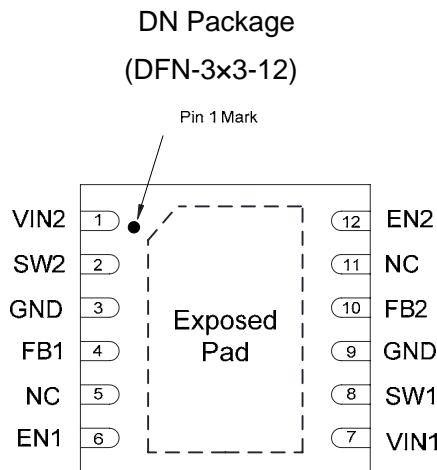


Figure 2. Pin Configuration of AP3423 (Top View)

### Pin Description

Pin Number	Pin Name	Description
1	VIN2	Power input supply of channel 2. Decouple this pin to GND with a capacitor
2	SW2	Internal power switch output of channel 2. Connect this pin with one terminal of the inductor
3, 9	GND	Power ground. Connect this pin as close as possible to $C_{IN}$ and $C_{OUT}$
4	FB1	Feedback voltage of channel 1. This pin is the inverting input of internal error amplifier. It senses the converter output voltage through an external resistor divider. The internal reference voltage is 0.6V, which determines the output voltage through the resistor divider
5, 11	NC	No connection
6	EN1	Chip enable of channel 1 (Active high)
7	VIN1	Power input supply of channel 1. Decouple this pin to GND with a capacitor
8	SW1	Internal power switch output of channel 1. Connect this pin with one terminal of the inductor
10	FB2	Feedback voltage of channel 2. This pin is the inverting input of internal error amplifier. It senses the converter output voltage through an external resistor divider. The internal reference voltage is 0.6V, which determines the output voltage through the resistor divider
12	EN2	Chip enable of channel 2 (Active high)

## 1.2A, 1.4MHz, Dual Synchronous DC-DC Buck Converter AP3423

### Functional Block Diagram

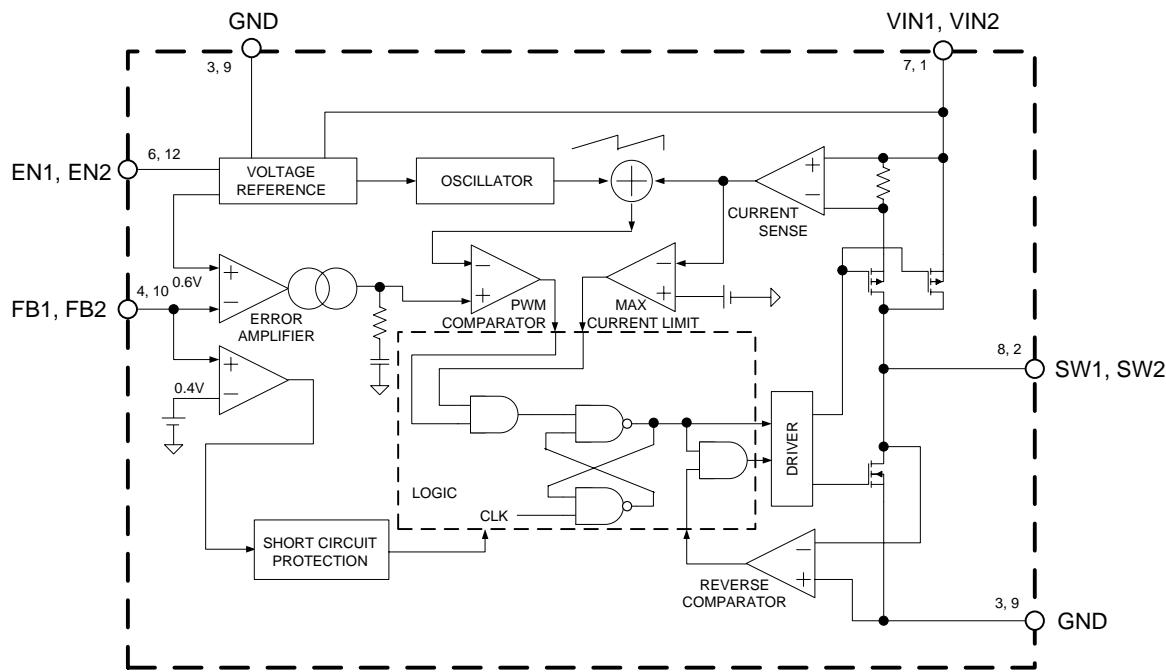
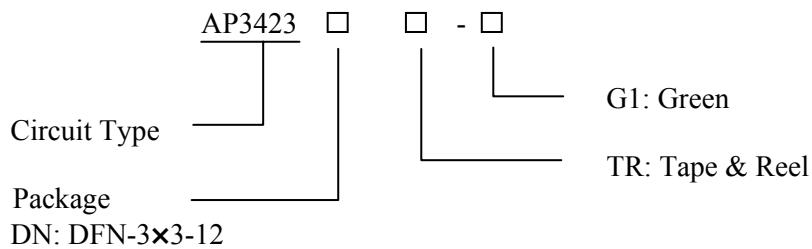


Figure 3. Functional Block Diagram of AP3423

### Ordering Information



Package	Temperature Range	Part Number	Marking ID	Packing Type
DFN-3x3-12	-40 to 85°C	AP3423DNTR-G1	PA	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "G1" suffix in the part number, are RoHS compliant and green.

**1.2A, 1.4MHz, Dual Synchronous DC-DC Buck Converter AP3423****Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value	Unit
VIN1,VIN2 Pin Voltage	V <sub>IN</sub>	-0.3 to 6	V
FB1, FB2 Pin Voltage	V <sub>FB</sub>	-0.3 to V <sub>IN</sub> +0.3	V
EN1, EN2 Pin Voltage	V <sub>EN</sub>	-0.3 to V <sub>IN</sub> +0.3	V
SW1, SW2 Pin Voltage	V <sub>SW</sub>	-0.3 to V <sub>IN</sub> +0.3	V
Thermal Resistance	θ <sub>JA</sub>	60	°C/W
Operating Junction Temperature	T <sub>J</sub>	150	°C
Storage Temperature	T <sub>STG</sub>	-65 to 150	°C
Lead Temperature (Soldering, 10sec)	T <sub>LEAD</sub>	260	°C
ESD (Machine Model)		200	V
ESD (Human Body Model)		2000	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

**Recommended Operating Conditions**

Parameter	Symbol	Min	Max	Unit
Input Voltage	V <sub>IN</sub>	2.5	5.5	V
Maximum Output Current	I <sub>OUT(MAX)</sub>	1.2		A
Operating Ambient Temperature	T <sub>A</sub>	-40	85	°C

**1.2A, 1.4MHz, Dual Synchronous DC-DC Buck Converter AP3423****Electrical Characteristics**

$V_{IN}=3.3V$ ,  $V_{OUT}=2.5V$ ,  $T_A=25^\circ C$ , unless otherwise specified.

Parameters	Symbol	Conditions	Min	Typ	Max	Unit
CHANNEL 1 and CHANNEL 2						
Input Voltage	$V_{IN}$		2.5		5.5	V
Quiescent Current	$I_Q$	$V_{FB}=0.65V$		62	100	$\mu A$
Shutdown Supply Current	$I_{STBY}$	$V_{EN}=GND$		0.1	1	$\mu A$
Reference Voltage	$V_{REF}$	For Adjustable Output Voltage	0.588	0.6	0.612	V
Feedback Bias Current	$I_{FB}$	$V_{FB}=V_{IN}$	-0.1		+0.1	$\mu A$
Output Voltage Accuracy	$\Delta V_{OUT}$		-2		+2	%
PMOSFET $R_{ON}$	$R_{DS(ON)_P}$	$I_{SW}=200mA$		0.28		$\Omega$
NMOSFET $R_{ON}$	$R_{DS(ON)_N}$	$I_{SW}=-200mA$		0.25		$\Omega$
Switch Current Limit	$I_{LIM}$	$V_{FB}=0.55V$	1.5	2.0		A
EN Pin Threshold	$V_H$		1.5			V
	$V_L$				0.4	
UVLO Threshold	$V_{UVLO}$	$V_{IN}$ Rising		2.3		V
UVLO Hysteresis	$V_{HYS}$			0.2		
Oscillator Frequency	$f_{OSC}$		1.12	1.4	1.68	MHz
Max. Duty Cycle	$D_{MAX}$	$V_{FB}=0V$	100			%
Min. Duty Cycle	$D_{MIN}$	$V_{FB}=6.5V$			0	
SW Leakage Current , N-MOS		$V_{IN}=V_{SW}=3.3V$		0.1		$\mu A$
Soft-start Time	t			1		ms
Thermal Shutdown	$T_{OTSD}$			160		$^\circ C$
Thermal Shutdown Hysteresis	$T_{HYS}$			20		$^\circ C$

**1.2A, 1.4MHz, Dual Synchronous DC-DC Buck Converter AP3423**
**Typical Performance Characteristics**

$V_{IN}=3.3V$ ,  $V_{OUT}=2.5V$ ,  $T_A=25^\circ C$ , unless otherwise specified.

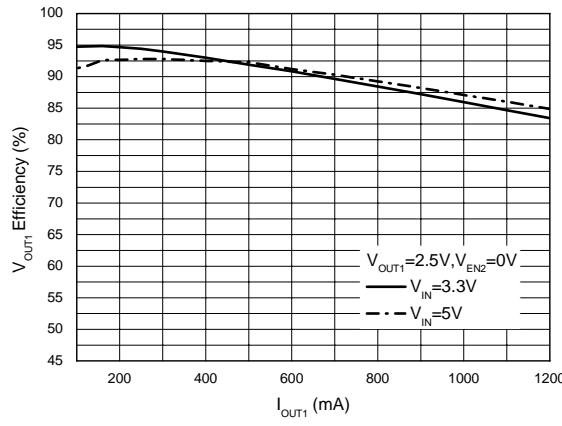


Figure 4.  $V_{OUT1}$  Efficiency vs.  $I_{OUT1}$

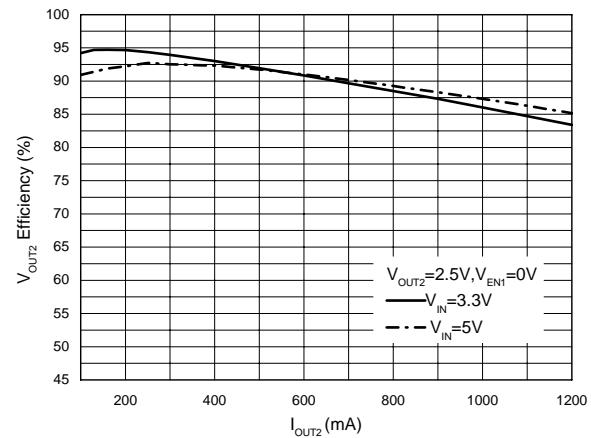


Figure 5.  $V_{OUT2}$  Efficiency vs.  $I_{OUT2}$

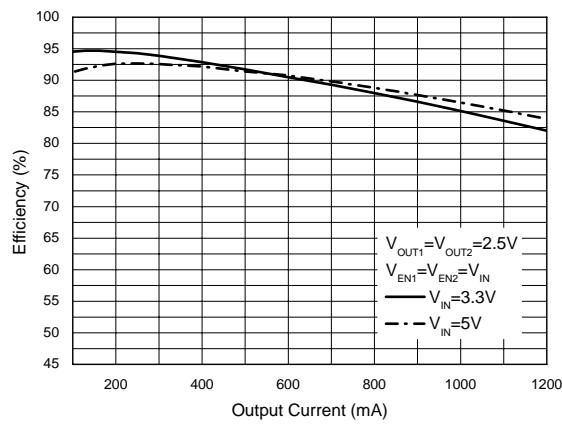


Figure 6. Efficiency vs. Output Current

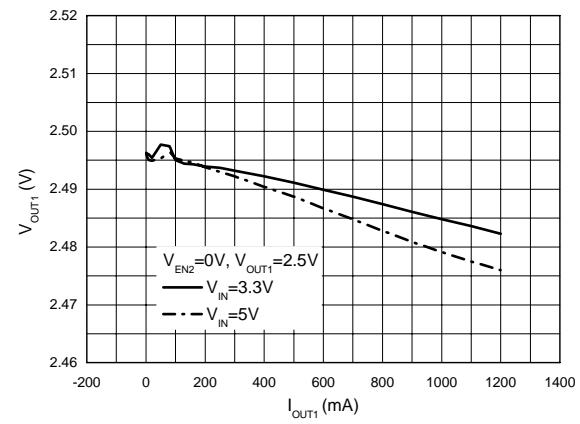


Figure 7.  $V_{OUT1}$  vs.  $I_{OUT1}$

## 1.2A, 1.4MHz, Dual Synchronous DC-DC Buck Converter AP3423

### Typical Performance Characteristics (Continued)

$V_{IN}=3.3V$ ,  $V_{OUT}=2.5V$ ,  $T_A=25^\circ C$ , unless otherwise specified.

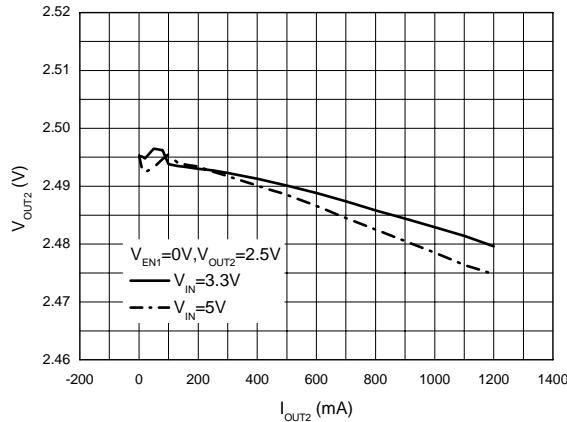


Figure 8.  $V_{OUT2}$  vs.  $I_{OUT2}$

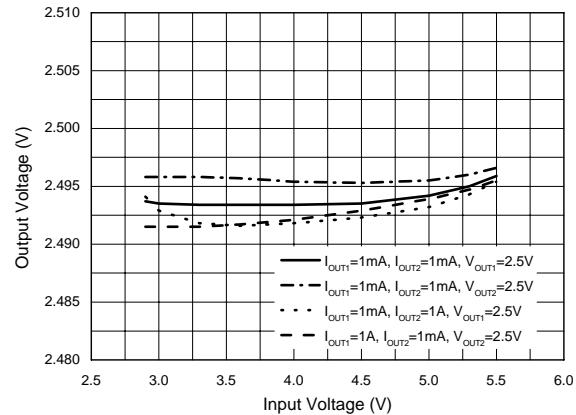


Figure 9. Output Voltage vs. Input Voltage

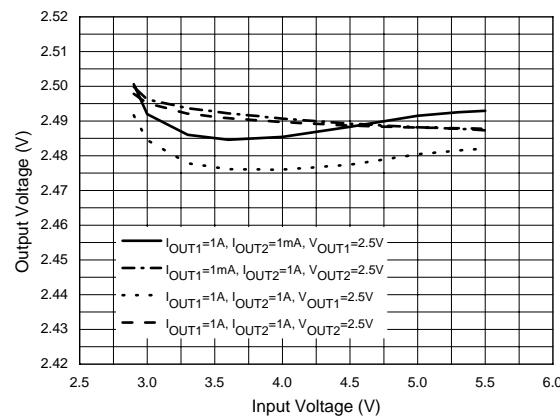


Figure 10. Output Voltage vs. Input Voltage

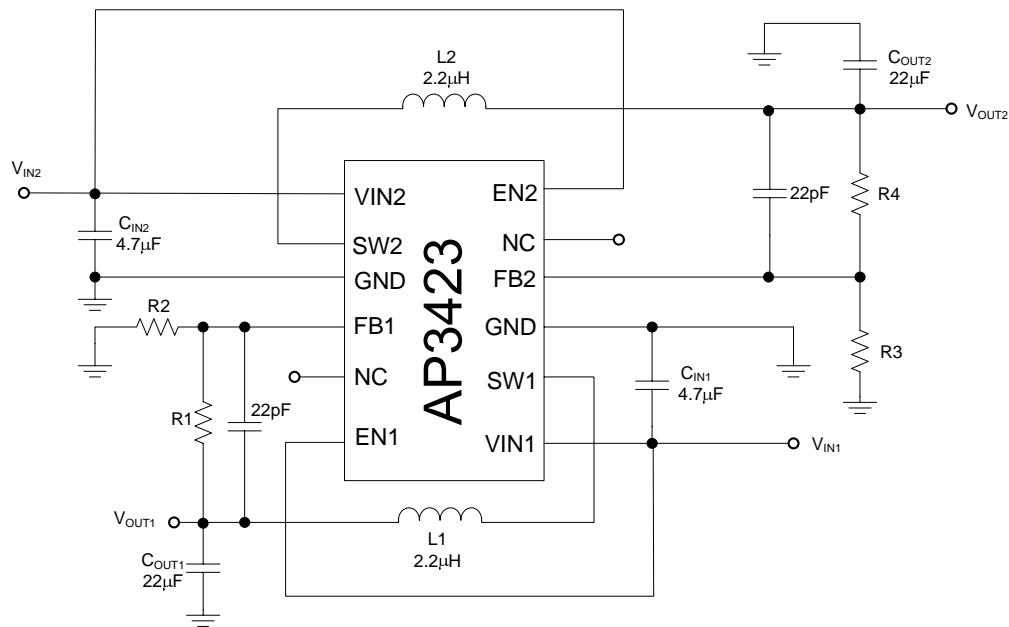
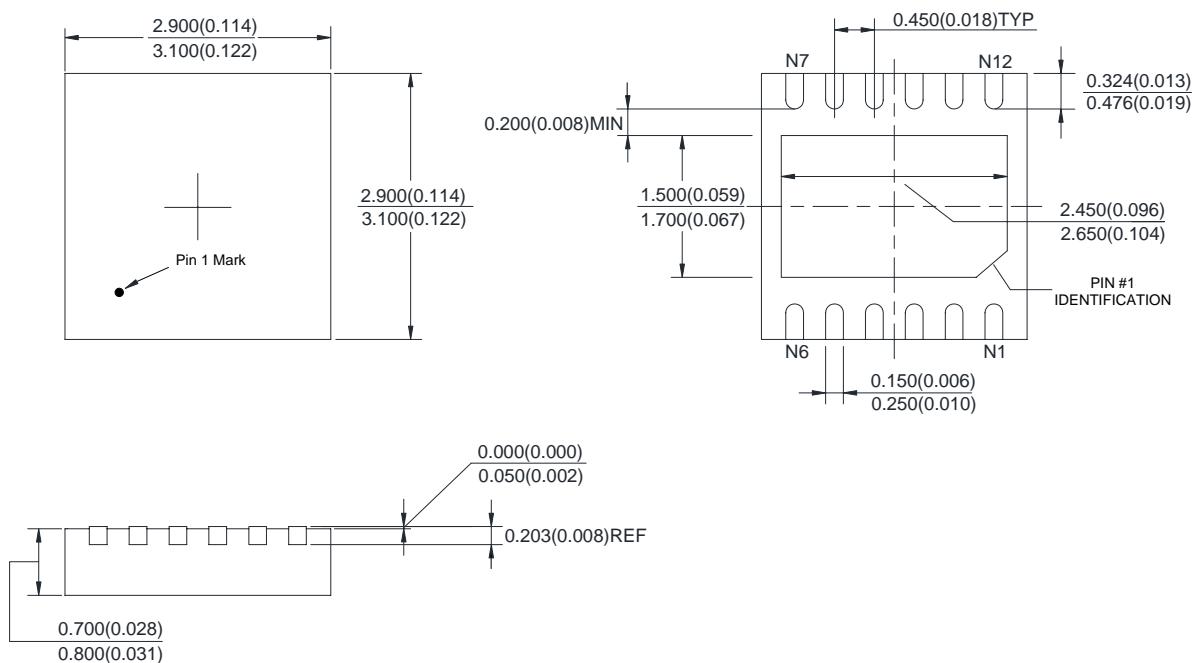
**1.2A, 1.4MHz, Dual Synchronous DC-DC Buck Converter AP3423****Typical Application**

Figure 11. Typical Application of AP3423

**1.2A, 1.4MHz, Dual Synchronous DC-DC Buck Converter AP3423****Mechanical Dimensions****DFN-3x3-12****Unit:mm(inch)**



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